

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









HMC253QS24 / 253QS24E

v04.0805



GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 2.5 GHz

Typical Applications

The HMC253QS24 / HMC253QS24E is ideal for DC - 2.5 GHz applications:

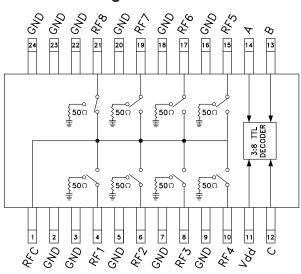
- CATV/DBS
- CDMA
- Cellular/PCS

Features

Low Insertion Loss (2 GHz): 1.3dB Single Positive Supply: Vdd = +5V

Integrated 3:8 TTL Decoder 24 Lead QSOP Package

Functional Diagram



General Description

The HMC253QS24 & HMC253QS24E are low-cost non-reflective SP8T switches in 24-lead QSOP packages featuring wideband operation from DC to 2.5 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility. A 3:8 decoder is integrated on the switch requiring only 3 control lines and a positive bias to select each path. The HMC253QS24 & HMC253QS24E SP8T will replace multiple configurations of SP4T and SPDT MMIC switches.

Electrical Specifications,

 $T_A = +25^{\circ}$ C, For TTL Control and Vdd = +5V in a 50 Ohm system

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz		1.1 1.3 1.8	1.5 1.7 2.4	dB dB dB
Isolation		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz	32 26 24	36 30 28		dB dB dB
Return Loss	"On State"	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz	14 9 6	18 12 8		dB dB dB
Return Loss (RF1-8)	"Off State"	0.3 - 2.5 GHz 0.5 - 2.5 GHz	7 10	10 13		dB dB
Input Power for 1 dB Compression		0.3 - 2.5 GHz	20	23		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.3 - 2.5 GHz	40	43		dBm
Switching Characteristics		0.3 - 2.5 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)				30 100		ns ns

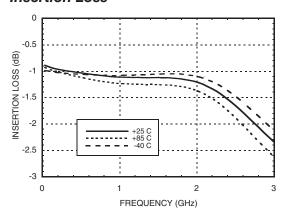


v04.0805

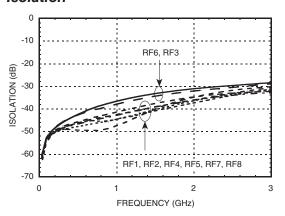


GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 2.5 GHz

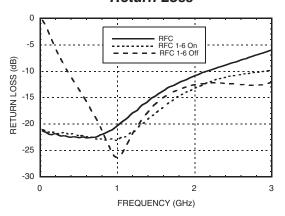
Insertion Loss



Isolation



Return Loss



Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%			
Vdd (Vdc)	Idd (Typ.) (mA)	Idd (Max.) (mA)	
+5.0	6.0	9.0	

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ 5 uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.

Truth Table

Control Input			Signal Path State
Α	В	С	RFCOM to:
Low	Low	Low	RF1
High	Low	Low	RF2
Low	High	Low	RF3
High	High	Low	RF4
Low	Low	High	RF5
High	Low	High	RF6
Low	High	High	RF7
High	High	High	RF8
Low High Low	Low Low High	High High High	RF5 RF6 RF7

NOTE:

DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8.



v04.0805



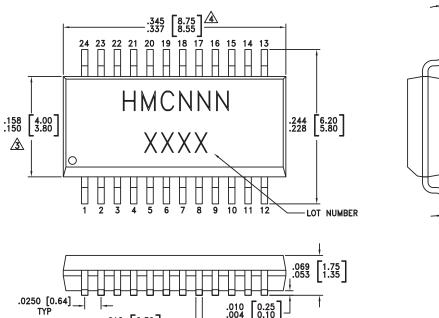
GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 2.5 GHz

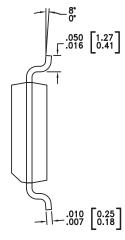
Absolute Maximum Ratings

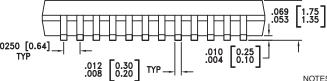
Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, C)	-0.5V to Vdd +1Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5V	+20 dBm (0.05 - 0.5 GHz) +24 dBm (0.5 - 2.5 GHz)



Outline Drawing







- 1. LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Leadframe Plating	MSL Rating	Package Marking [3]
HMC253QS24	Low Stress Injection Molded Plastic Silica and Silicon Impregnated	Sn/Pb Solder	MSL1 [1]	HMC253 XXXX
HMC253QS24E	RoHS-compliant Low Stress Injection Molded Plastic Silica and Silicon Impregnated	100% Matte Tin	MSL1 [2]	HMC253 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX

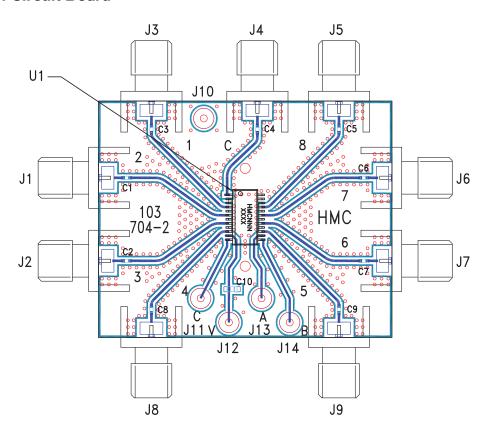


v04.0805



GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 2.5 GHz

Evaluation Circuit Board



List of Materials for Evaluation PCB 103706 [1]

Item	Description
J1 - J9	PCB Mount SMA Connector
J10 - J14	DC Pin
C1 - C9	100 pF Capacitor, 0402 Pkg.
C10	0.01 uF Capacitor, 0603 Pkg.
U1	HMC253QS24 / HMC253QS24E SP8T Switch
PCB [2]	103704 Eval Board

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^[2] Circuit Board Material: Rogers 4350